

## N-Channel JFETs

### Product Summary

Part Number	V <sub>GS(off)</sub> (V)	V <sub>(BR)GSS</sub> Min (V)	g <sub>fs</sub> Min (mS)	I <sub>DSS</sub> Max (mA)
2N4338	-0.3 to -1	-50	0.6	0.6
2N4339	-0.6 to -1.8	-50	0.8	1.5
2N4340	-1 to -3	-50	1.3	3.6
2N4341	-2 to -6	-50	2	9

For applications information see AN102, page 1, AN106, page 1.

### Features

- Low Cutoff Voltage: 2N4338 <1 V
- High Input Impedance
- Very Low Noise
- High Gain: A<sub>v</sub> = 80 @ 20 μA

### Benefits

- Full Performance from Low-Voltage Power Supply: Down to 1 V
- Low Signal Loss/System Error
- High System Sensitivity
- High-Quality Low-Level Signal Amplification

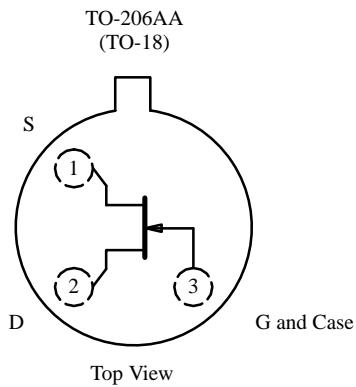
### Applications

- High-Gain, Low-Noise Amplifiers
- Low-Current, Low-Voltage Battery-Powered Amplifiers
- Infrared Detector Amplifiers
- Ultrahigh Input Impedance Pre-Amplifiers

### Description

The 2N4338/4339/4340/4341 n-channel JFETs are designed for sensitive amplifier stages at low- to mid-frequencies. Low cut-off voltages accommodate low-level power supplies and low leakage for improved system accuracy.

The TO-206AA (TO-18) package is hermetically sealed and suitable for military processing (see Military Information). For similar products in TO-226AA (TO-92) and TO-236 (SOT-23) packages, see the J/SST201 series data sheet.



### Absolute Maximum Ratings

Gate-Source/Gate-Drain Voltage .....	-50 V	Lead Temperature ( $\frac{1}{16}$ " from case for 10 sec.) .....	300°C
Forward Gate Current .....	50 mA	Power Dissipation <sup>a</sup> .....	300 mW
Storage Temperature .....	-65 to 200°C	Notes	
Operating Junction Temperature .....	-55 to 175°C	a.	Derate 2 mW/°C above 25°C

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70240. Applications information may also be obtained via FaxBack, request document #9102 and #9106.

## Specifications<sup>a</sup> for 2N4338 and 2N4339

Parameter	Symbol	Test Conditions	Typ <sup>b</sup>	Limits				Unit	
				2N4338		2N4339			
				Min	Max	Min	Max		
<b>Static</b>									
Gate-Source Breakdown Voltage	V <sub>(BR)GSS</sub>	I <sub>G</sub> = -1 μA, V <sub>DS</sub> = 0 V	-57	-50		-50		V	
Gate-Source Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 0.1 μA		-0.3	-1	-0.6	-1.8		
Saturation Drain Current <sup>c</sup>	I <sub>DSS</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V		0.2	0.6	0.5	1.5	mA	
Gate Reverse Current	I <sub>GSS</sub>	V <sub>GS</sub> = -30 V, V <sub>DS</sub> = 0 V T <sub>A</sub> = 150°C	-2 -4		-100		-100	pA	
Gate Operating Current <sup>c</sup>	I <sub>G</sub>	V <sub>DG</sub> = 15 V, I <sub>D</sub> = 0.1 mA	-2					pA	
Drain Cutoff Current	I <sub>D(off)</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = -5 V	2		50		50		
Gate-Source Forward Voltage <sup>d</sup>	V <sub>GS(F)</sub>	I <sub>G</sub> = 1 mA, V <sub>DS</sub> = 0 V	0.7					V	
<b>Dynamic</b>									
Common-Source Forward Transconductance	g <sub>fs</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 kHz		0.6	1.8	0.8	2.4	mS	
Common-Source Output Conductance	g <sub>os</sub>				5		15	μS	
Drain-Source On-Resistance	r <sub>ds(on)</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = 0 V, f = 1 kHz			2500		1700	Ω	
Common-Source Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz	5		7		7	pF	
Common-Source Reverse Transfer Capacitance	C <sub>rss</sub>		1.5		3		3		
Equivalent Input Noise Voltage <sup>d</sup>	̄e <sub>n</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 kHz	6					nV/√Hz	
Noise Figure	NF	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V f = 1 kHz, R <sub>G</sub> = 1 MΩ			1		1	dB	

## Specifications<sup>a</sup> for 2N4340 and 2N4341

Parameter	Symbol	Test Conditions	Typ <sup>b</sup>	Limits				Unit	
				2N4340		2N4341			
				Min	Max	Min	Max		
<b>Static</b>									
Gate-Source Breakdown Voltage	V <sub>(BR)GSS</sub>	I <sub>G</sub> = -1 μA, V <sub>DS</sub> = 0 V	-57	-50		-50		V	
Gate-Source Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 0.1 μA		-1	-3	-2	-6		
Saturation Drain Current <sup>c</sup>	I <sub>DSS</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V		1.2	3.6	3	9	mA	
Gate Reverse Current	I <sub>GSS</sub>	V <sub>GS</sub> = -30 V, V <sub>DS</sub> = 0 V T <sub>A</sub> = 150°C	-2 -4		-100		-100	pA	
Gate Operating Current <sup>c</sup>	I <sub>G</sub>	V <sub>DG</sub> = 15 V, I <sub>D</sub> = 0.1 mA	-2					pA	
Drain Cutoff Current	I <sub>D(off)</sub>	V <sub>DS</sub> = 15 V V <sub>GS</sub> = -5 V V <sub>GS</sub> = -10 V	2		50				
Gate-Source Forward Voltage <sup>d</sup>	V <sub>GS(F)</sub>		3				70	V	

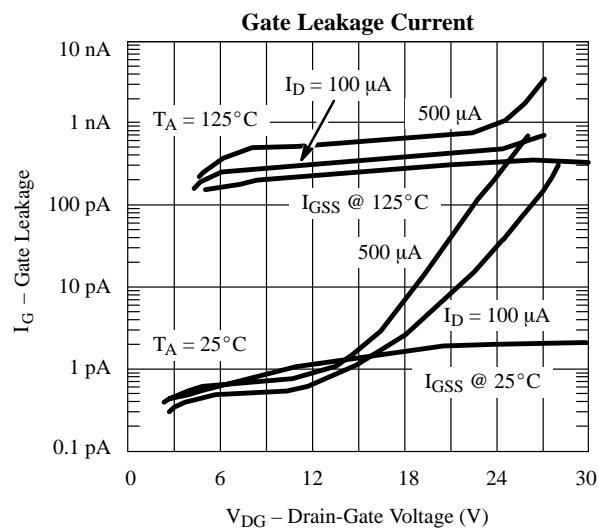
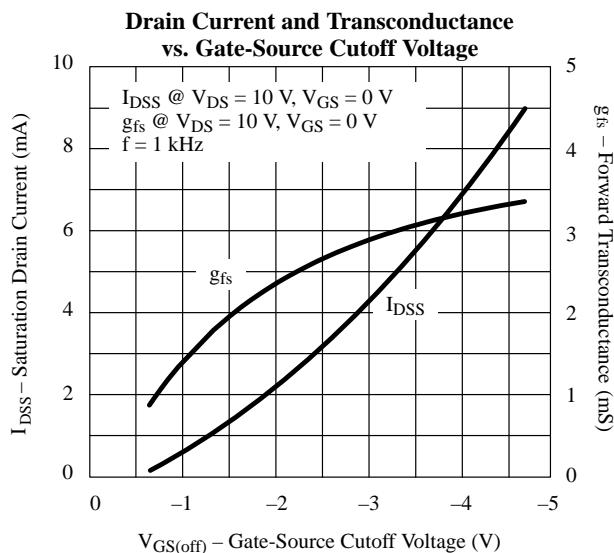
## Specifications<sup>a</sup> for 2N4340 and 2N4341

Parameter	Symbol	Test Conditions	Typ <sup>b</sup>	Limits				Unit	
				2N4340		2N4341			
				Min	Max	Min	Max		
<b>Dynamic</b>									
Common-Source Forward Transconductance	$g_{fs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ kHz}$		1.3	3	2	4	mS	
Common-Source Output Conductance	$g_{os}$				30		60	$\mu\text{S}$	
Drain-Source On-Resistance	$r_{ds(on)}$	$V_{DS} = 0 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ kHz}$			1500		800	$\Omega$	
Common-Source Input Capacitance	$C_{iss}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	5		7		7	pF	
Common-Source Reverse Transfer Capacitance	$C_{rss}$		1.5		3		3		
Equivalent Input Noise Voltage <sup>d</sup>	$\bar{e}_n$	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ kHz}$	6					$\frac{\text{nV}}{\sqrt{\text{Hz}}}$	
Noise Figure	NF	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}$ $f = 1 \text{ kHz}, R_G = 1 \text{ M}\Omega$			1		1	dB	

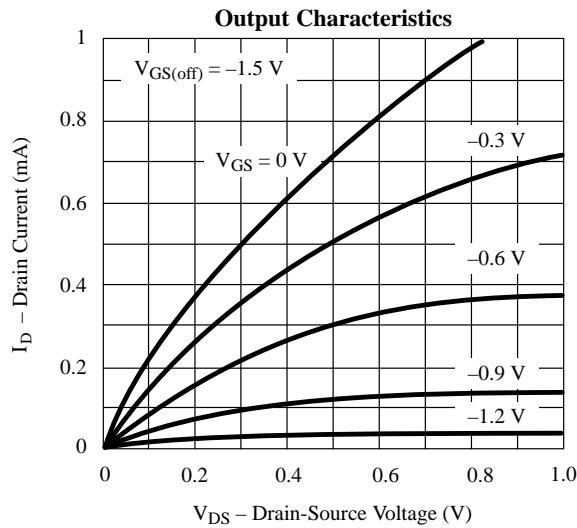
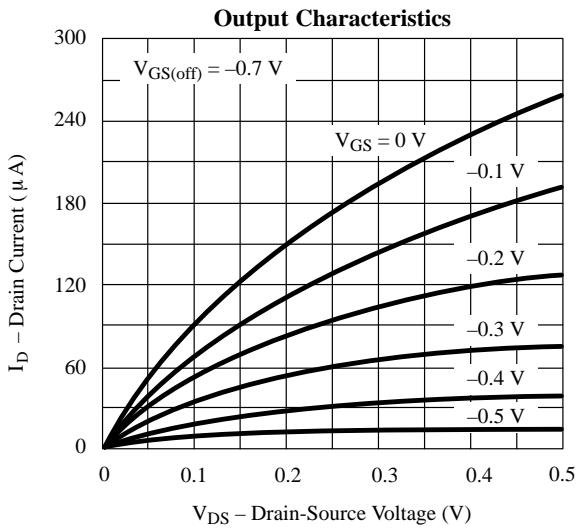
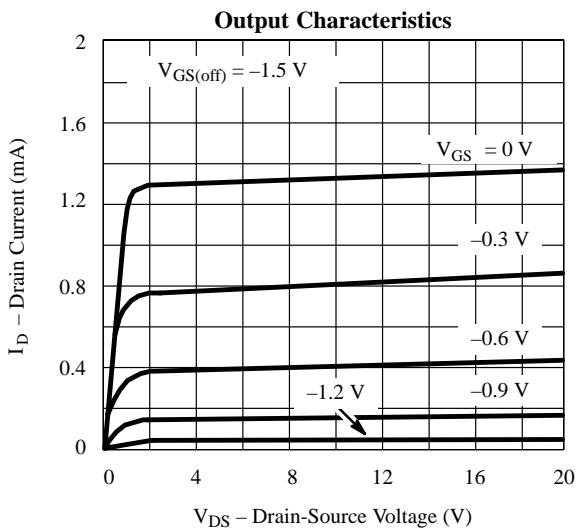
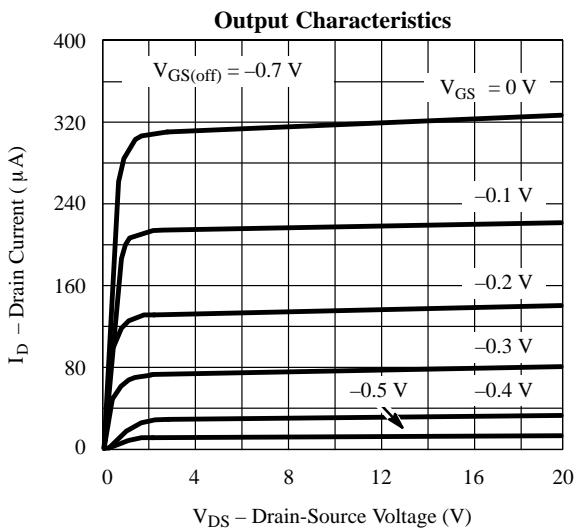
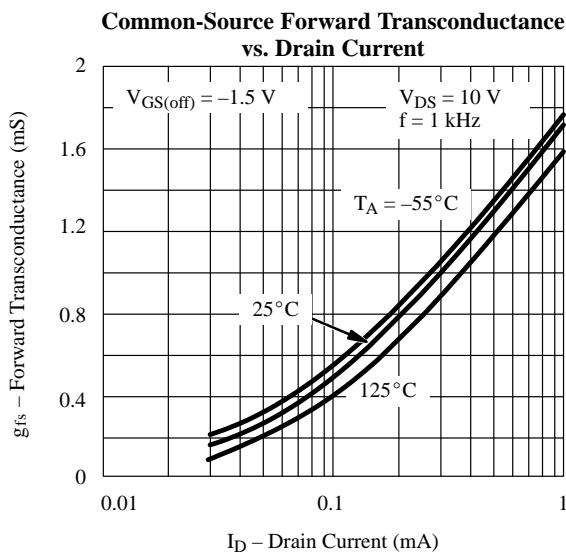
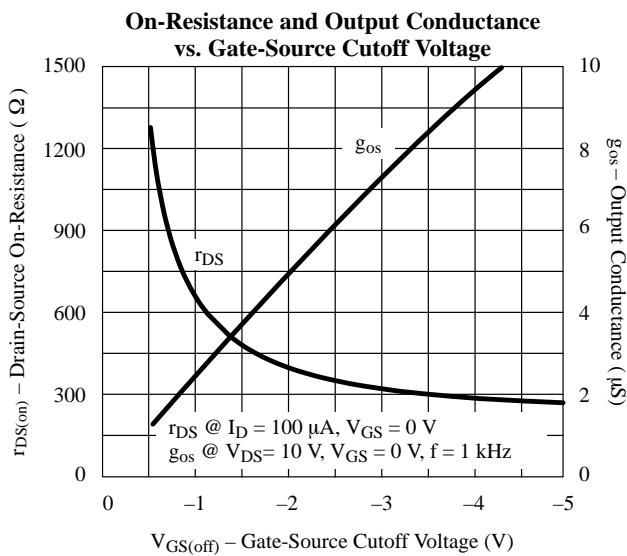
Notes

- a.  $T_A = 25^\circ\text{C}$  unless otherwise noted. NPA
- b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- c. Pulse test: PW  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 3\%$ .
- d. This parameter not registered with JEDEC.

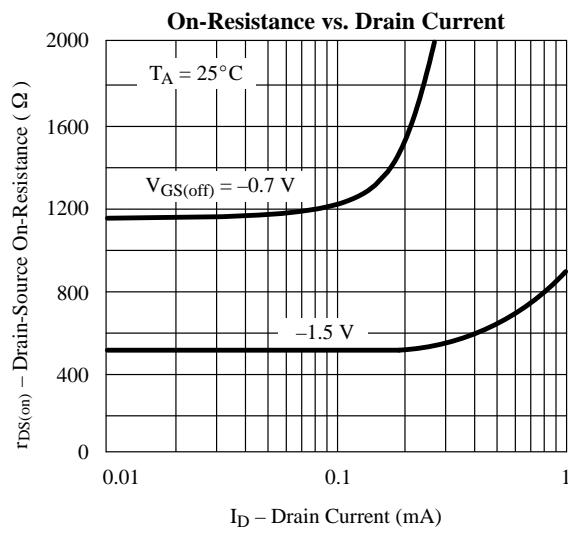
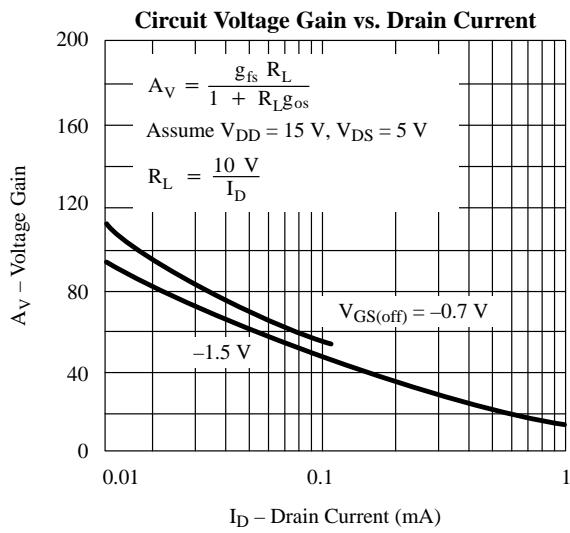
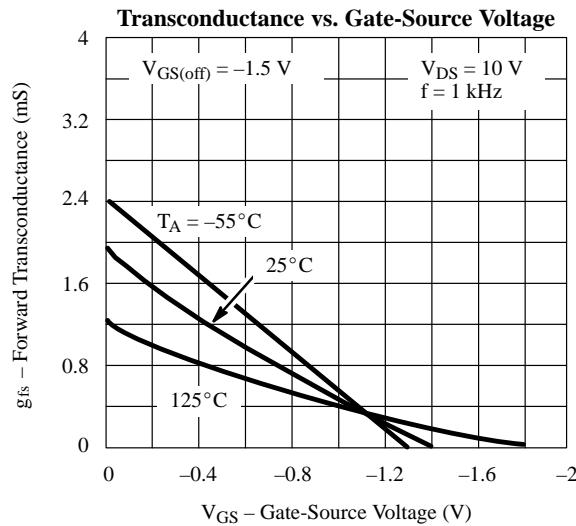
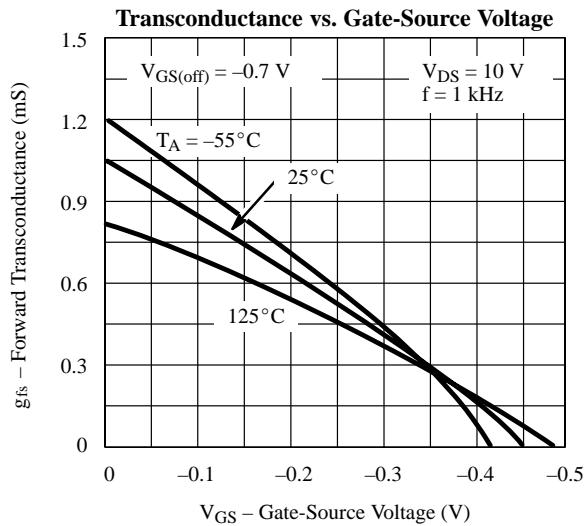
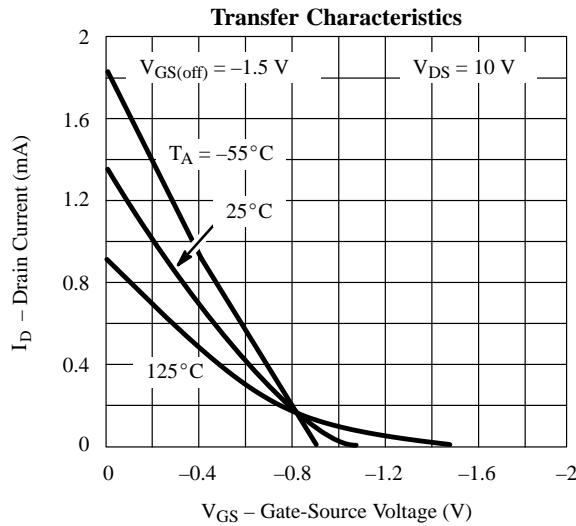
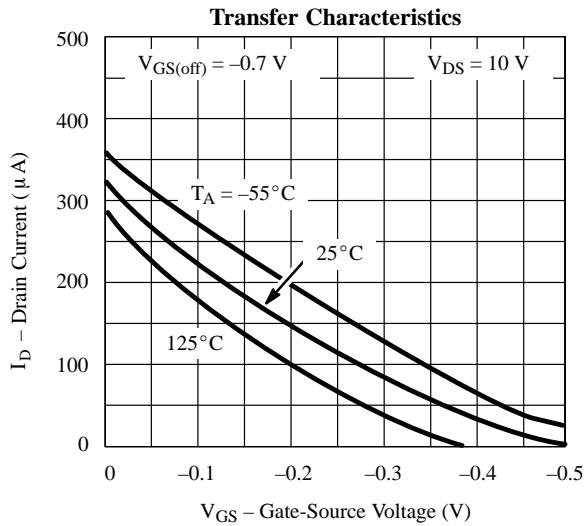
## Typical Characteristics



## Typical Characteristics (Cont'd)



## Typical Characteristics (Cont'd)



## Typical Characteristics (Cont'd)

